



HMC626LP5 / 626LP5E

0.5 dB LSB GaAs MMIC 6-BIT DIGITAL VARIABLE GAIN AMPLIFIER, DC - 1 GHz

Typical Applications

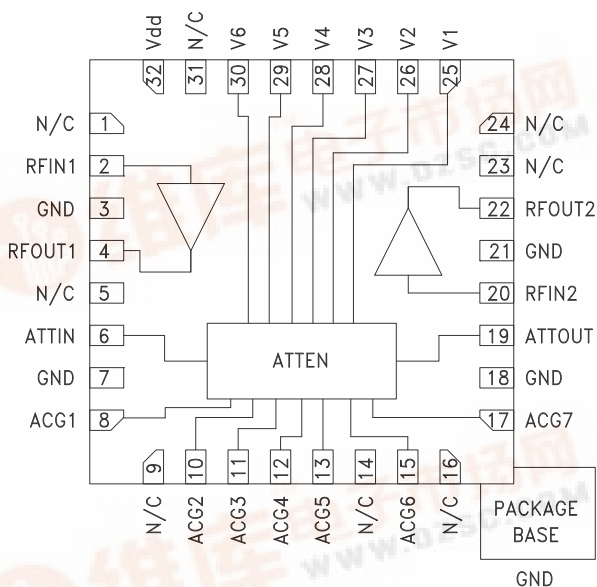
The HMC626LP5(E) is ideal for:

- IF & RF Applications
- Cellular/3G Infrastructure
- WiBro / WiMAX / 4G
- Microwave Radio & VSAT
- Test Equipment and Sensors

Features

- +8.5 dB to +40 dB Gain Control in 0.5 dB Steps
- High Output IP3: +36 dBm
- ±0.25 dB Typical Gain Step Error
- Single +5V Supply
- 32 Lead 5x5mm SMT Package: 25mm²

Functional Diagram

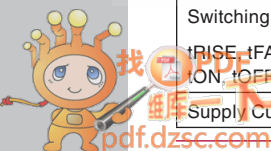


General Description

The HMC626LP5(E) is a digitally controlled variable gain amplifier which operates from DC to 1 GHz, and can be programmed to provide anywhere from 8.5 dB, to 40 dB of gain, in 0.5 dB steps. The HMC626LP5(E) delivers noise figure of 4 dB in its maximum gain state, with output IP3 of up to +36 dBm in any state. This single positive control line per bit digital attenuator incorporates off chip AC ground capacitors for near DC operation, making it suitable for a wide variety of RF and IF applications. The HMC626LP5(E) is housed in a RoHS compliant 5x5 mm QFN leadless package, and requires no external matching components.

Electrical Specifications, $T_A = +25^\circ C$, $V_{dd} = V_s = +5V$, $V_{ctl} = 0 / +5V$

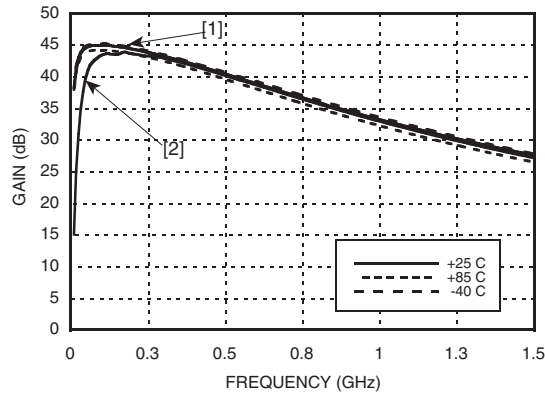
Parameter	Frequency	Min.	Typ.	Max.	Units
Gain (Maximum Gain State)	DC - 0.5 GHz	37	42.5		dB
	0.5 - 1.0 GHz	30	35.0		dB
Gain Control Range			31.5		dB
Input Return Loss			20		dB
Output Return Loss			15		dB
Attenuation Accuracy: (Referenced to Maximum Gain State) All Attenuation States	0.5 - 1.0 GHz	± (0.15 + 3% of Atten. Setting) Max.			dB
Output Power for 1 dB Compression	DC - 1.0 GHz		20		dBm
Output Third Order Intercept Point (Two-Tone Input Power= 0 dBm Each Tone)	DC - 1.0 GHz		36		dBm
Noise Figure	DC - 1.0 GHz		4		dB
Switching Characteristics					
TRISE, TFALL (10/90% RF)	DC - 1.0 GHz		130		ns
TON, TOFF (50% CTL to 10/90% RF)			140		ns
Supply Current	DC - 1.0 GHz		176		mA



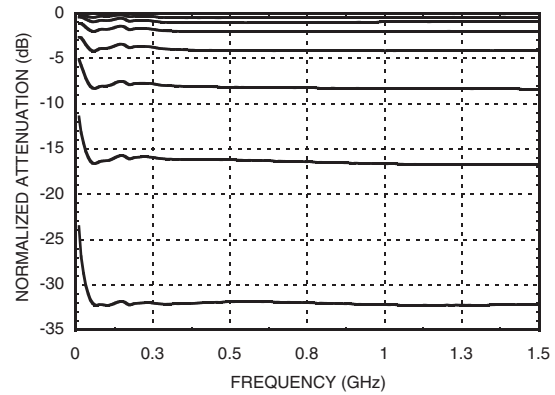
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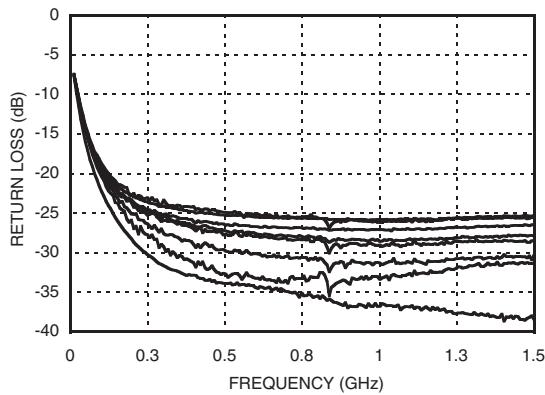
Gain vs. Frequency^[1]



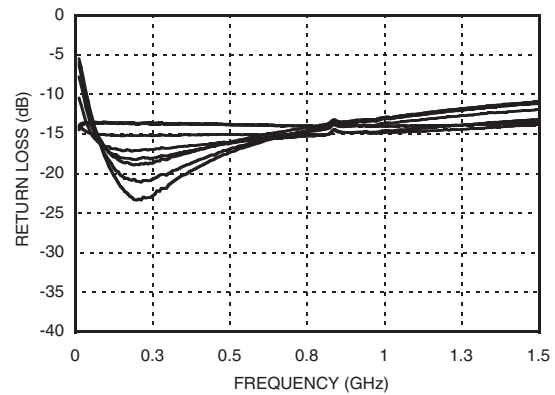
Normalized Attenuation
(Only Major States are Shown)



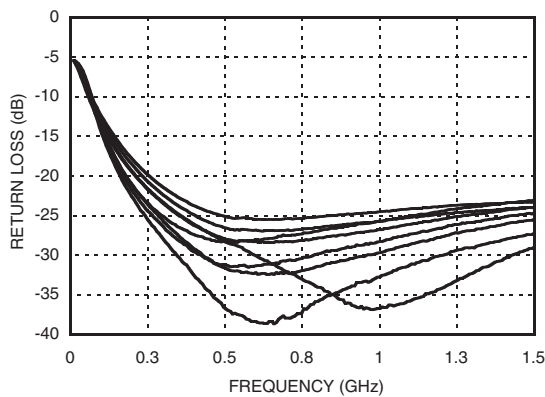
Input Return Loss^[1]
(Only Major States are Shown)



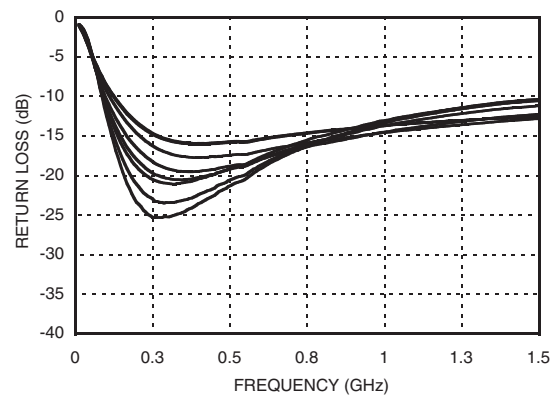
Output Return Loss^[1]
(Only Major States are Shown)



Input Return Loss^[2]
(Only Major States are Shown)



Output Return Loss^[2]
(Only Major States are Shown)



[1] Tested with broadband bias tee on output J2, C7, C8 = 10,000pF ; L1 = 680nH

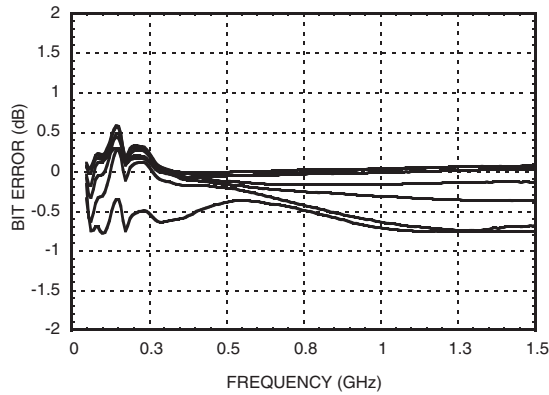
[2] Data taken on eval board as described in data sheet



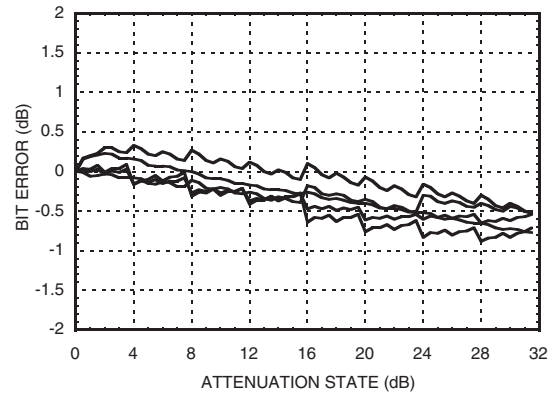
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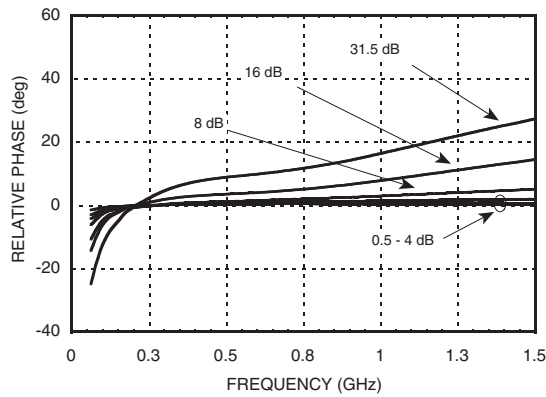
Bit Error vs. Frequency [2]
(Only Major States are Shown)



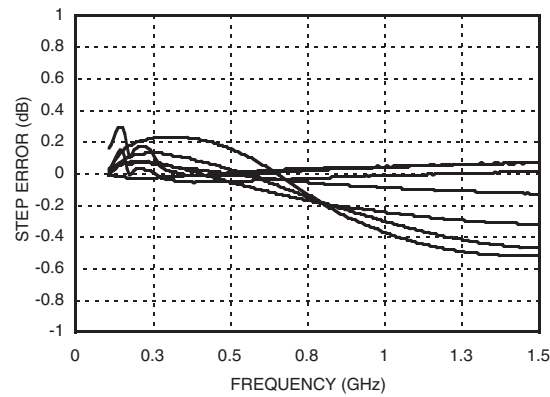
Bit Error vs. Attenuation State [2]



Normal Relative Phase vs. Frequency [2]
(Only Major States are Shown)



Step Error vs. Frequency [2]
(Only Major States are Shown)



[1] Tested with broadband bias tee on output J2, C7, C8 = 10,000pF ; L1 = 680nH
[2] Data taken on eval board as described in data sheet


Bias Voltage & Current

Vdd (V)	Idd (Typ.) (mA)
+4.5	4.7
+5.0	5.0
+5.5	5.3
Vs (V)	Is (mA)
+5.0	176

Control Voltage

State	Bias Condition
Low	0 to +0.8 Vdc @ -5 uA Typ.
High	+ 2.0 to + 5.0 Vdc @ 40 uA Typ.

Note: Vdd = +5V

Truth Table

Control Voltage Input						Gain Relative to Maximum Gain
V6	V5	V4	V3	V2	V1	
High	High	High	High	High	High	Reference 0 dB
High	High	High	High	High	Low	-0.5 dB
High	High	High	High	Low	High	-1 dB
High	High	High	Low	High	High	-2 dB
High	High	Low	High	High	High	-4 dB
High	Low	High	High	High	High	-8 dB
Low	High	High	High	High	High	-16 dB
Low	Low	Low	Low	Low	Low	-31.5 dB

Any combination of the above states will provide a reduction in gain approximately equal to the sum of the bits selected.



MICROWAVE CORPORATION v02.0907



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Absolute Maximum Ratings

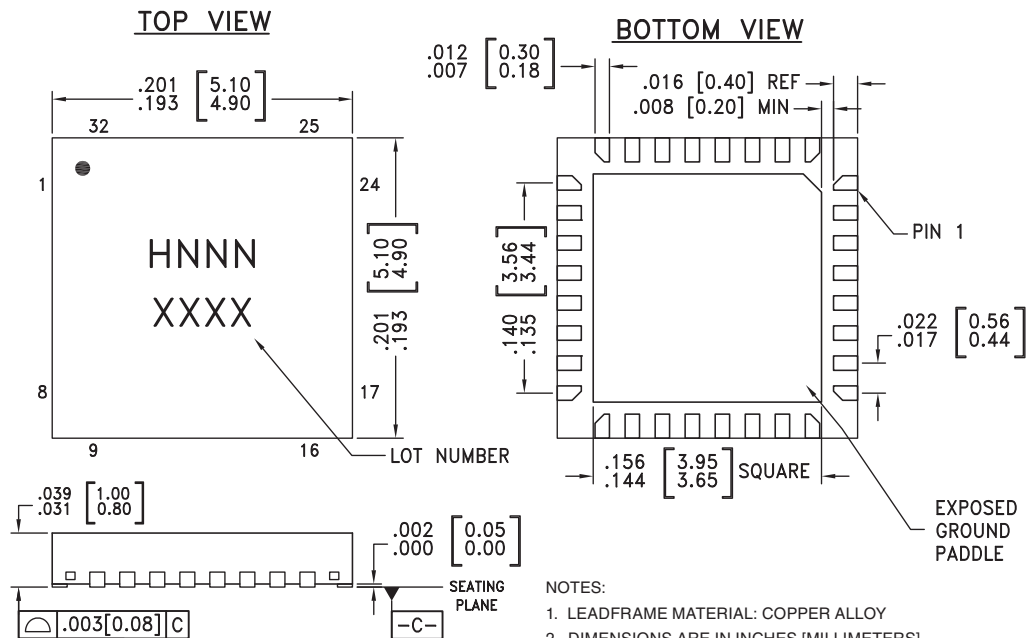
RF Input Power [1]	12.5 dBm (T = +85 °C)
Bias Voltage (Vdd)	+5.5 Vdc
Collector Bias Voltage (Vcc)	5.5 Vdc
Channel/Junction Temperature	150 °C
Continuous P _{diss} (T = 85 °C) (derate 7.7 mW/°C above 85 °C) [1]	0.593 °C/W
Thermal Resistance	110 °C/W
Storage Temperature	-65 to +150 °C
Operating Temperature	-40 to +85 °C

[1] At max gain setting



ELECTROSTATIC SENSITIVE DEVICE
OBSERVE HANDLING PRECAUTIONS

Outline Drawing



NOTES:

1. LEADFRAME MATERIAL: COPPER ALLOY
2. DIMENSIONS ARE IN INCHES [MILLIMETERS]
3. LEAD SPACING TOLERANCE IS NON-CUMULATIVE.
4. PAD BURR LENGTH SHALL BE 0.15mm MAXIMUM.
PAD BURR HEIGHT SHALL BE 0.05mm MAXIMUM.
5. PACKAGE WARP SHALL NOT EXCEED 0.05mm.
6. ALL GROUND LEADS AND GROUND PADDLE MUST BE SOLDERED TO PCB RF GROUND.
7. REFER TO HITTITE APPLICATION NOTE FOR SUGGESTED LAND PATTERN.

Package Information

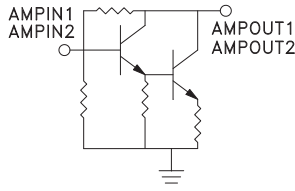

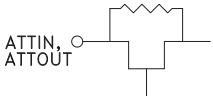
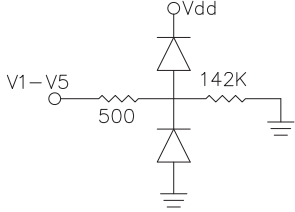
Part Number	Package Body Material	Lead Finish	MSL Rating	Package Marking [3]
HMC626LP5	Low Stress Injection Molded Plastic	Sn/Pb Solder	MSL1 [1]	H626 XXXX
HMC626LP5E	RoHS-compliant Low Stress Injection Molded Plastic	100% matte Sn	MSL1 [2]	H626 XXXX

[1] Max peak reflow temperature of 235 °C

[2] Max peak reflow temperature of 260 °C

[3] 4-Digit lot number XXXX

Pin Descriptions

Pin Number	Function	Description	Interface Schematic
1, 5, 9, 14, 16, 23, 24, 31	N/C	These pins may be connected to RF/DC ground. Performance will not be affected.	
2, 20	AMPIN1, AMPIN2	This pin is DC coupled. An off chip DC blocking capacitor is required. Amplifier bias provided via external bias tee as shown in application circuit.	
4, 22	AMPOUT1, AMPOUT2	RF output and DC bias (Vcc) for the output stage of the amplifier.	
3, 7, 18, 21	GND	These pins and package bottom must be connected to RF/DC ground.	
6, 19	ATTIN, ATTOUT	These pins are DC coupled and matched to 50 Ohms. Blocking capacitors are required. Select value based on lowest frequency of operation.	
8, 10, 11, 12, 13, 15, 17	ACG1, ACG2, ACG3, ACG4, ACG5, ACG6, ACG7	External capacitors to ground is required. Select value for lowest frequency of operation. Place capacitor as close to pins as possible.	
25 - 30	V1 - V6	See truth table, control voltage table and timing diagram.	
32	Vdd	Supply voltage	



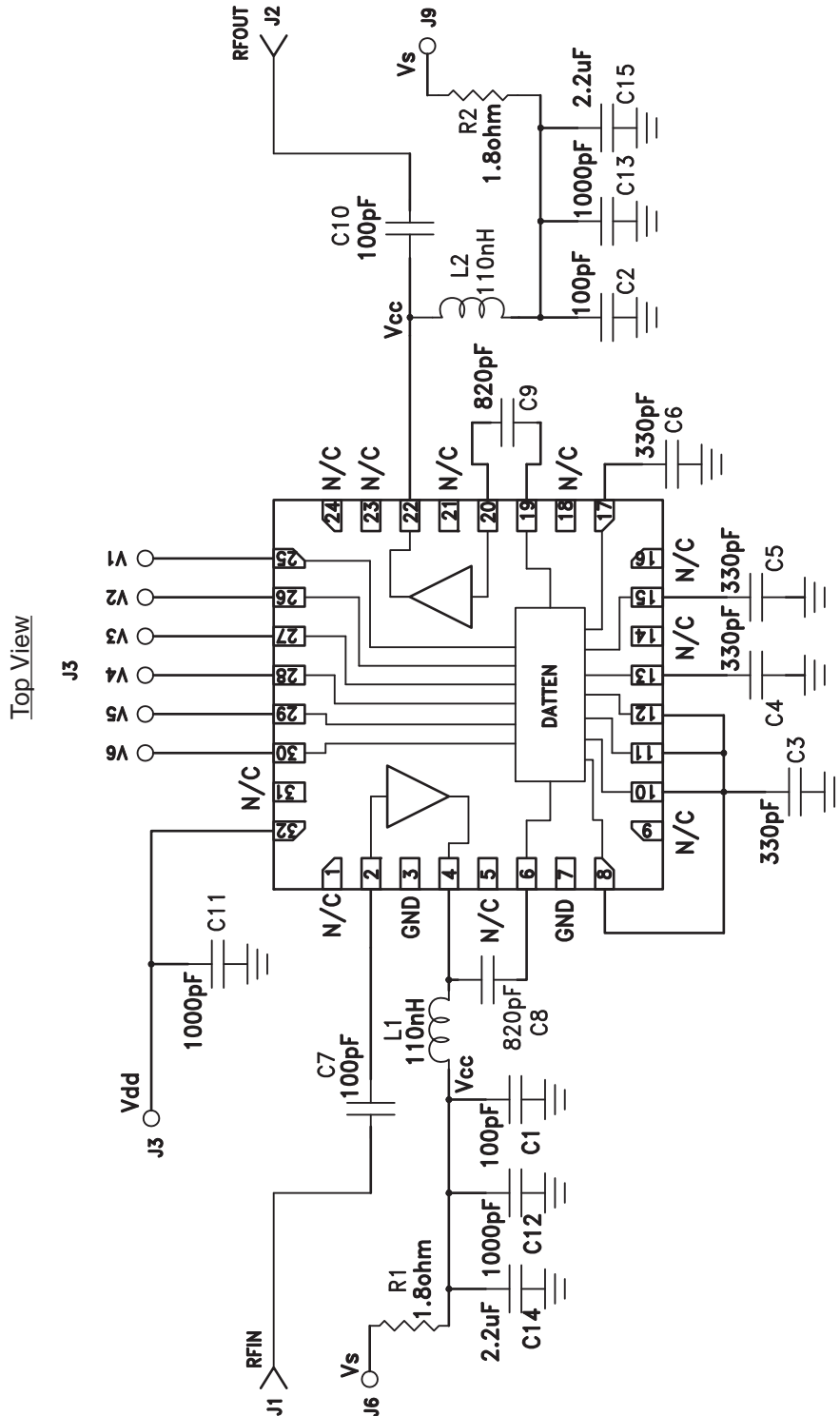
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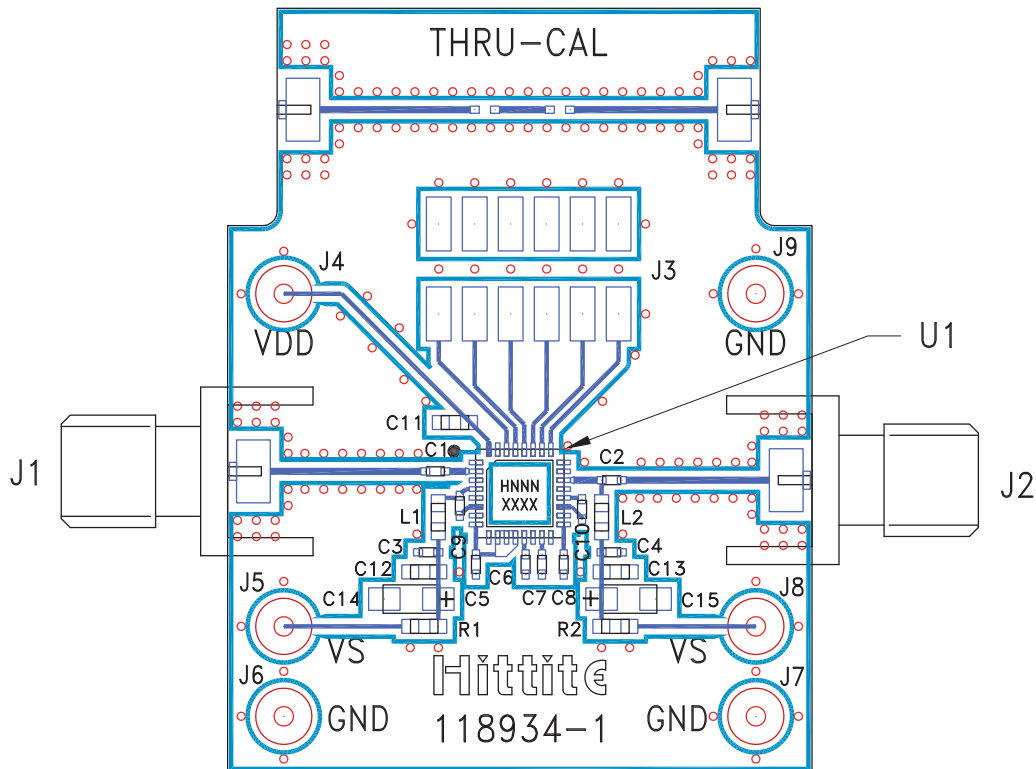
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Application Circuit



Evaluation PCB



List of Materials for Evaluation PCB 117355 [1]

Item	Description
J1 - J2	PCB Mount SMA Connector
J3	12 Pin DC Connector
J4 - J9	DC Pin
C1, C2, C9, C10	820 pF Capacitor, 0402 Pkg.
C3, C4	100 pF Capacitor, 0402 Pkg.
C5 - C8	330 pF Capacitor, 0402 Pkg.
C11 - C13	1000 pF Capacitor, 0402 Pkg.
C14, C15	2.2 μ F Capacitor, CASEA Pkg.
R1, R2	1.8 Ohm Resistor, 0603 Pkg.
L1, L2	110 nH Inductor, 0603 Pkg.
U1	HMC626LP5(E) Variable Gain Amplifier
PCB [2]	117354 Evaluation PCB

[1] Reference this number when ordering complete evaluation PCB

[2] Circuit Board Material: Rogers 4350

The circuit board used in the final application should use RF circuit design techniques. Signal lines should have 50 ohm impedance while the package ground leads and exposed paddle should be connected directly to the ground plane similar to that shown. A sufficient number of via holes should be used to connect the top and bottom ground planes. The evaluation circuit board shown is available from Hittite upon request.